Vishay Semiconductors

HEXFRED[®] Ultrafast Soft Recovery Diode, 60 A

FEATURES

- Fast recovery time characteristic
- Electrically isolated base plate
- Large creepage distance between terminal
- · Simplified mechanical designs, rapid assembly
- UL approved file E78996
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level

DESCRIPTION/APPLICATIONS

The dual diode series configuration (HFA60FA120P) is used for output rectification or freewheeling/clamping operation and high voltage application.

The semiconductor in the SOT-227 package is isolated from the copper base plate, allowing for common heatsinks and compact assemblies to be built.

These modules are intended for general applications such as HV power supplies, electronic welders, motor control and inverters.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Cathode to anode voltage	V _R		1200	V	
Continuous forward current	I _F	T _C = 110 °C	30		
Single pulse forward current	I _{FSM}	T _J = 25 °C	350	A	
Maximum repetitive forward current	I _{FRM}	Rated V_{R_i} square wave, 20 kHz, T_C = 60 °C	110		
Maximum neuror dissinction	Р	T _C = 25 °C	216	W	
Maximum power dissipation	PD	T _C = 100 °C	86	VV	
RMS isolation voltage	V _{ISOL}	Any terminal to case, t = 1 minute	2500	V	
Operating junction and storage temperature range	T _J , T _{Stg}		- 55 to + 150	°C	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA	1200	-	-		
Forward voltage V _{FM}		I _F = 30 A	-	2.2	3.0	V	
	V _{FM}	I _F = 60 A	-	2.7	3.8		
		I _F = 60 A, T _J = 150 °C	-	3.4	-		
		V _R = V _R rated	-	1.0	75	μA	
Reverse leakage current I _{RM}		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	2.7	10	mA	



1200 V

2.2 V

123 ns

30 A at 110 °C

PRODUCT SUMMARY

VR

V_F (typical)

trr (typical)

I_{F(DC)} at T_C





RoHS

COMPLIANT



Vishay Semiconductors HEXF

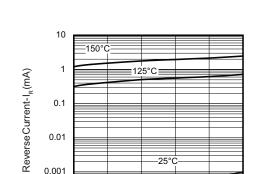
HEXFRED®
Ultrafast Soft Recovery Diode, 60 A

DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
	T _J = 25 °C		-	123	-		
Reverse recovery time	t _{rr}	T _J = 125 °C		-	188	-	ns
	T _J = 25 °C	$I_F = 50 A$	-	12	-	_	
Peak recovery current	I _{RRM}	T _J = 125 °C	dI _F /dt = - 200 A/μs V _R = 200 V	-	17	-	A
Deverse weeks weeks weeks	Q _{rr}	T _J = 25 °C		-	675	-	nC
Reverse recovery charge		T _J = 125 °C		-	1500	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Junction to case, single leg conducting	P		-	-	0.58	
Junction to case, both legs conducting	– R _{thJC}		-	-	0.29	°C/W
Case to heatsink	R _{thCS}	Flat, greased and surface	-	0.05	-	
Weight			-	30	-	g
Mounting torque			-	1.3	-	Nm



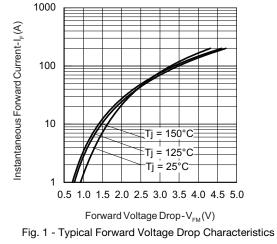
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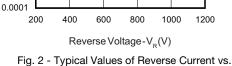


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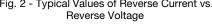
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25



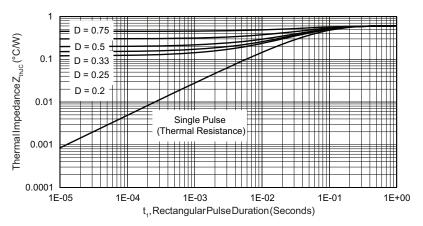
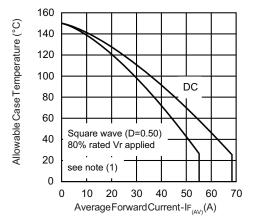
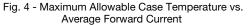
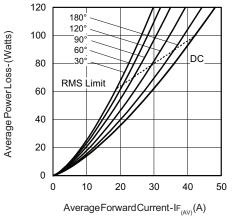


Fig. 3 - Maximum Thermal Impedance ZthJC Characteristics









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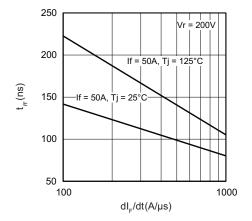


Fig. 6 - Typical Reverse Recovery Time vs. dl_F/dt

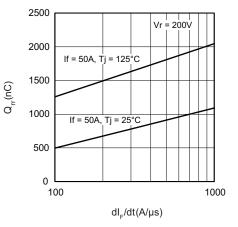


Fig. 7 - Typical Stored Charge vs. dl_F/dt

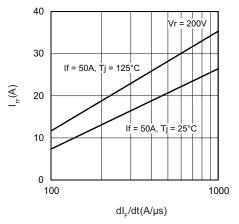


Fig. 8 - Typical Peak Recovery Current vs. dl_F/dt

Note



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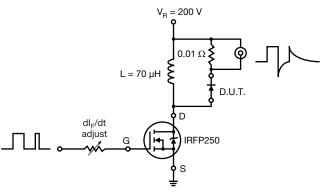


Fig. 9 - Reverse Recovery Parameter Test Circuit

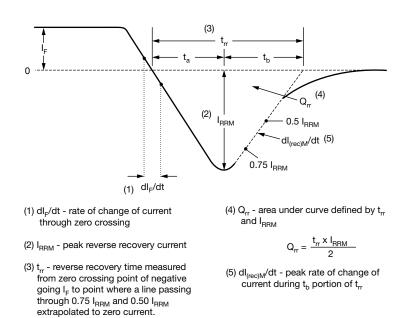


Fig. 10 - Reverse Recovery Waveform and Definitions

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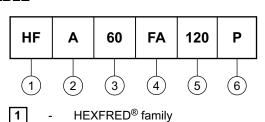
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ORDERING INFORMATION TABLE

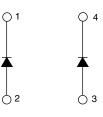
Device code

6



- HEXFRED[®] family
 - Process designator (A = Electron irradiated)
- Average current (60 = 60 A)
- Package outline (FA = SOT-227)
- Voltage rating (120 = 1200 V)
- P = Lead (Pb)-free

CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95036				
Packaging information	www.vishay.com/doc?95037			

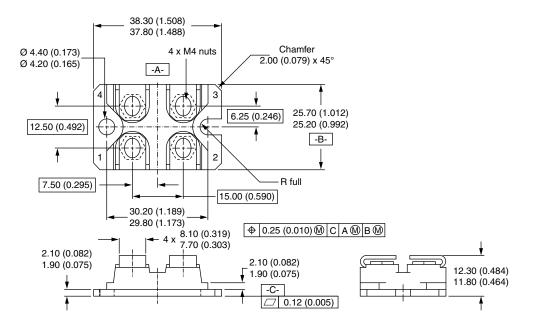


Outline Dimensions

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SOT-227

DIMENSIONS in millimeters (inches)



Notes

- Dimensioning and tolerancing per ANSI Y14.5M-1982
- Controlling dimension: millimeter



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